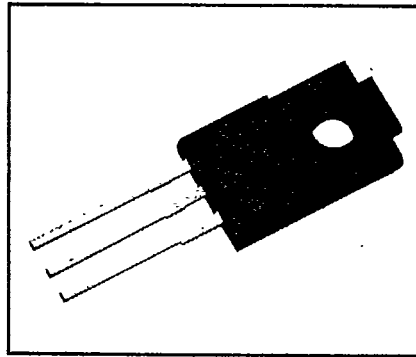
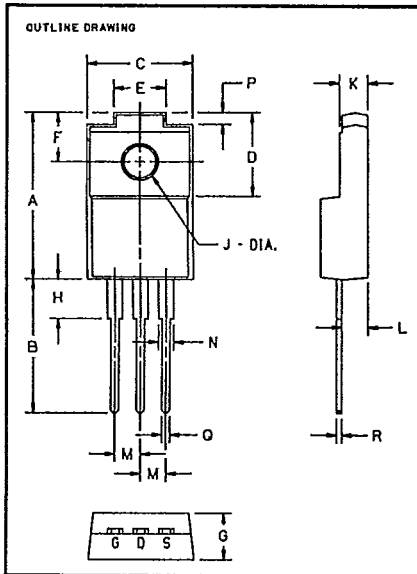


POWEREX**J934****J935****Tentative**

Powerex, Inc., Hillis Street, Youngwood, Pennsylvania 15697 (412) 925-7272

**Single EXMOS™
MOSFET****8 Amperes/250-300 Volts**

J934, J935
Single EXMOS™ MOSFET
 8 Amperes/250-300 Volts

Description

Powerex Single EXMOS™ MOSFET Transistors are designed for use in applications requiring hi-frequency switching and low loss control.

Features:

- ☐ TO-220F Isolated Package
- ☐ Vertical DMOS Construction
- ☐ Low Drive Requirement
- ☐ No Second Breakdown

Applications:

- ☐ AC Motor Control
- ☐ UPS Inverters
- ☐ Switch Mode Power Supply
- ☐ PWM Regulators

Ordering Information

Select the complete four digit module part number you desire from the table i.e. J935 is a 300 Volt, 8 Ampere Single EXMOS™ MOSFET, and J934 is a 250 Volt, 8 Ampere Single EXMOS™ MOSFET.

250-300 Volts J934, J935
Outline Drawing

Dimension	Inches	Millimeters
A	.669 ± .012	17 ± 0.3
B	.531 Min.	13.5 Min.
C	.413 Max.	10.5 Max.
D	.335 ± .012	8.5 ± 0.3
E	.205 ± .008	5.2 ± 0.2
F	.197 ± .012	5.0 ± 0.3
G	.185 Max.	4.7 Max.
H	.157 Max.	4.0 Max.
J	.126 + .008/- .000	3.2 + 0.2/- 0.0
K	.110 ± .008	2.8 ± 0.2
L	.102 ± .008	2.6 ± 0.2
M	.100 ± .010	2.54 ± 0.25
N	.059 Max.	1.5 Max.
P	.047 ± .012	1.2 ± 0.3
Q	.031 ± .004	0.8 ± 0.1
R	.020 ± .004	0.5 ± 0.1

Type	V _{DS} Volts (250-300)	Current Rating Amperes (8)
J934	—	—
J935	—	—



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Powerex, Inc., Hillis Street, Youngwood, Pennsylvania 15697 (412) 925-7272

J934

J935

Single EXMOS™ MOSFET

8 Amperes/250-300 Volts

Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	J934/J935	Units
Junction Temperature	T_J	-55 to 150	$^\circ\text{C}$
Storage Temperature	T_{STG}	-55 to 150	$^\circ\text{C}$
Drain Source Voltage, $I_D = 1\text{mA}$, $V_{GS} = 0\text{V}$	V_{DS}	250/300	Volts
Gate-Source Voltage	V_{GS}	± 30	Volts
Continuous Drain Current	I_D	6	Amperes
Continuous Source Current	I_S	6	Amperes
Pulsed Drain Current Repetitive	I_{DM}	24	Amperes
Power Dissipation	P_T	40	Watts
V isolation	V_{RMS}	1500	Volts
Max. Mounting Torque, Mounting Screw (M3)	—	7	in.-lb.

Static Electrical Characteristics $T_C, T_J = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	J934 Typ.	Max.	Min.	J935 Typ.	Max.	Units
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = V_{DSS}, V_{GS} = 0\text{V}$	—	—	1	—	—	1	mA
Gate Source Leakage Current	$\pm I_{GSS}$	$V_{GS} = \pm 30\text{V}, V_{DS} = 0\text{V}$	—	—	0.1	—	—	0.1	μA
Gate Source Threshold Voltage	$V_{GS(th)}$	$I_D = 1\text{mA}, V_{DS} = 10\text{V}$	2	3	4	2	3	4	Volts
Drain Source On State Resistance	$R_{DS(on)}$	$V_{GS} = 10\text{V}, I_D = 4\text{A}$	—	.4	.52	—	.45	.6	Ω
Drain Source On State Voltage	$V_{DS(on)}$	$V_{GS} = 10\text{V}, I_D = 4\text{A}$	—	1.6	2.1	—	1.8	2.4	Volts
Thermal Resistance, Junction to Case	$R_{\theta JC}$	—	—	—	3.13	—	—	3.13	$^\circ\text{C/W}$

Source Drain Diode Characteristics $T_C, T_J = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	J934/J935 Typ.	Max.	Units
Source-Drain Voltage	V_{SD}	$I_S = 4\text{A}, V_{GS} = 0\text{V}$	—	0.9	—	Volts
Reverse Recovery Time	t_{rr}	$I_S = 8\text{A}, dI_S/dt = -20\text{A}/\mu\text{s}, V_{GS} = 0\text{V}$	—	400	—	ns

Dynamic Electrical Characteristics $T_C, T_J = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	J934/J935 Typ.	Max.	Units
Forward Transconductance	g_{fs}	$I_D = 4\text{A}, V_{DS} = 10\text{V}$	2	4	—	mhos
Input Capacitance	C_{iss}	—	—	1000	—	pF
Output Capacitance	C_{oss}	$V_{GS} = 0\text{V}, V_{DS} = 25\text{V}, f = 1\text{MHz}$	—	200	—	pF
Reverse Transfer Capacitance	C_{rss}	—	—	50	—	pF
Turn On Time (Note 1)	t_{on}	$V_{DD} = 150\text{V}, I_D = 4\text{A}, V_{GS} = 10\text{V}$	—	70	140	ns
Turn Off Time (Note 1)	t_{off}	$R_{GEN} = R_{GS} = 50\Omega$	—	150	300	ns

Note 1: Turn on Time (t_{on}) = Turn on Delay ($t_{d(on)}$) + Rise Time (t_r)
Turn-off Time (t_{off}) = Turn Off Delay ($t_{d(off)}$) + Fall Time (t_f)

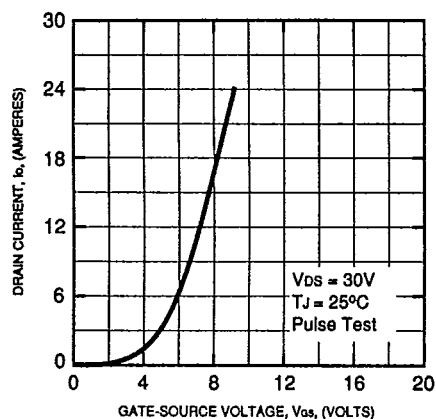
POWEREX

Tentative

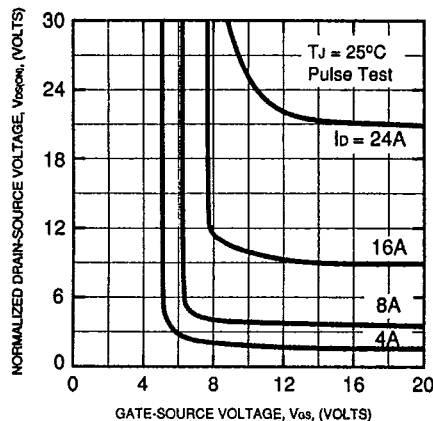
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J934
J935
Single EXMOS™ MOSFET
8 Amperes/250-300 Volts

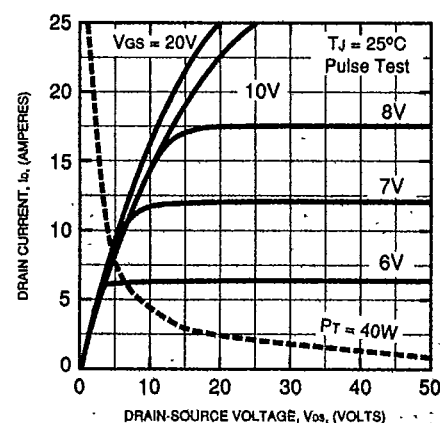
**TRANSFER CHARACTERISTICS
(TYPICAL)
J934**



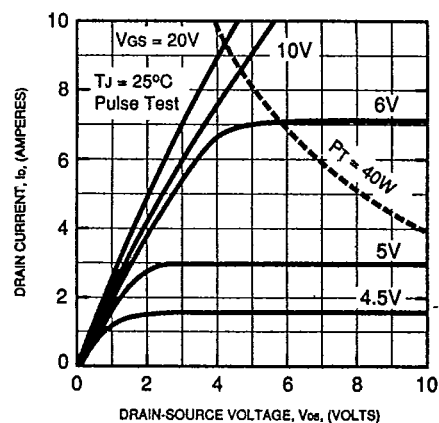
**NORMALIZED DRAIN-SOURCE
ON-STATE VOLTAGE (TYPICAL)
J934**



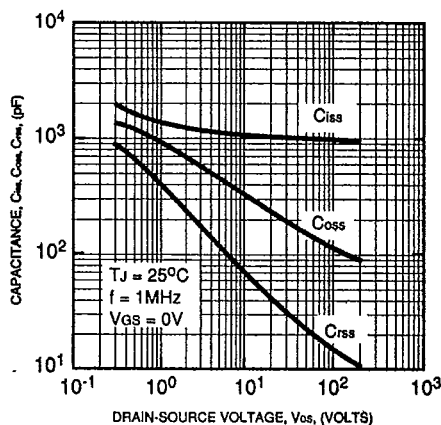
**COMMON SOURCE OUTPUT
CHARACTERISTICS (TYPICAL)
J934**



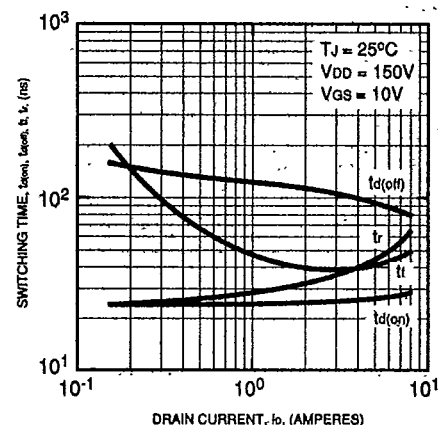
**COMMON SOURCE OUTPUT
CHARACTERISTICS (TYPICAL)
J934**



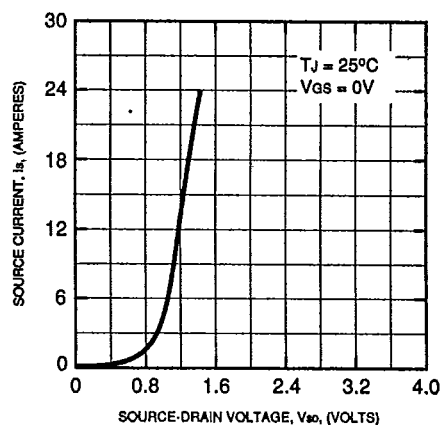
**CAPACITANCE VS. DRAIN-SOURCE VOLTAGE
(TYPICAL)
J934**



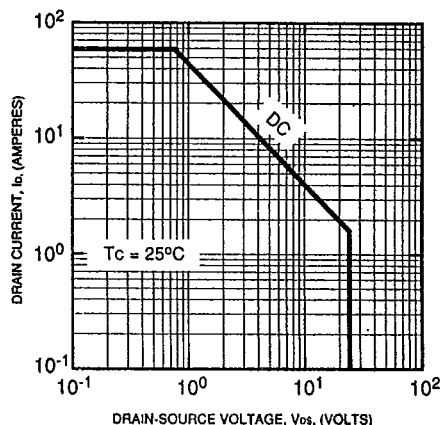
**SWITCHING CHARACTERISTICS
(TYPICAL)
J934**



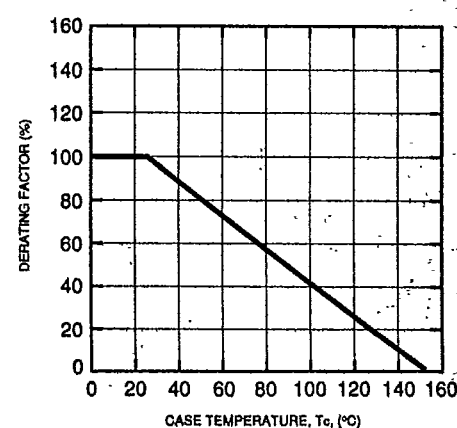
**SOURCE-DRAIN DIODE
FORWARD CHARACTERISTICS (TYPICAL)
J934**



**FORWARD BIAS SAFE OPERATING AREA
(S.O.A.)
J934**



**TEMPERATURE DERATING FACTOR
OF SAFE OPERATING AREA (S.O.A.)
J934**



POWEREX

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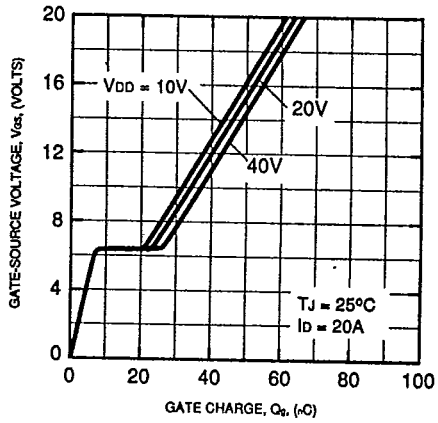
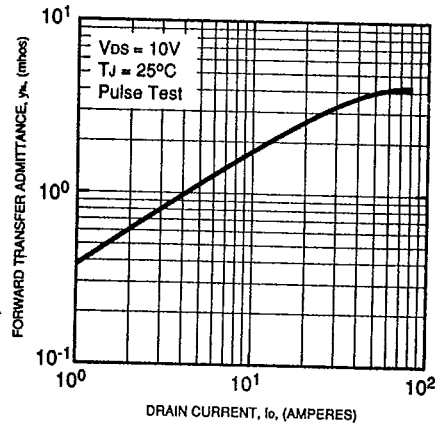
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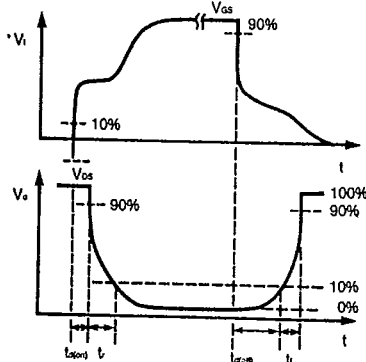
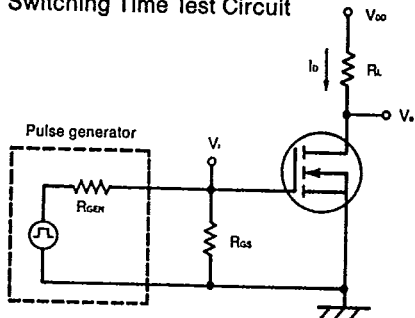
J935

Single EXMOS™ MOSFET

8 Amperes/250-300 Volts

GATE CHARGE VS. V_{GS}
(TYPICAL)
J934FORWARD TRANSFER ADMITTANCE VS.
DRAIN CURRENT (TYPICAL)
J934

Switching Time Test Circuit



Notice: MOS devices are susceptible to damage from electrostatic charge. Reasonable precautions in handling should be observed.

POWEREX

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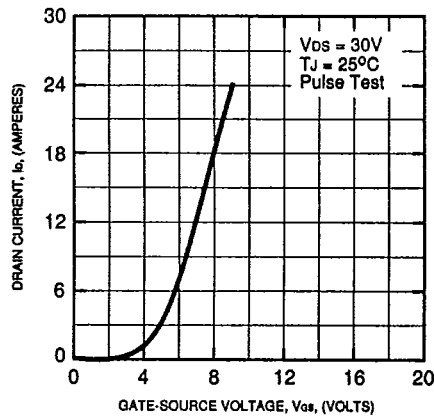
J934

J935

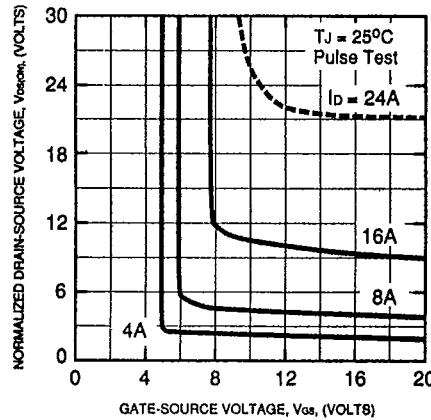
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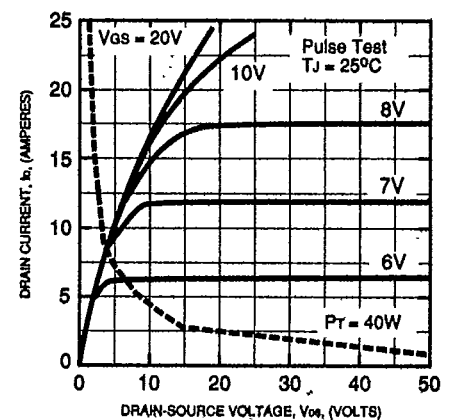
TRANSFER CHARACTERISTICS
(TYPICAL)
J935



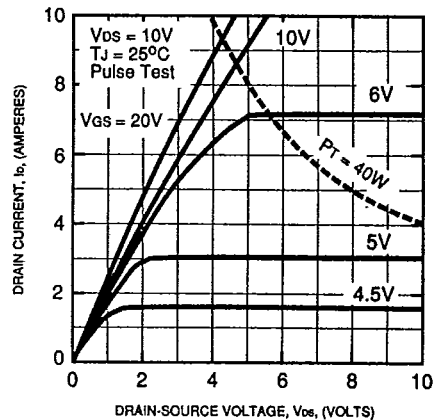
NORMALIZED DRAIN-SOURCE
ON-STATE VOLTAGE (TYPICAL)
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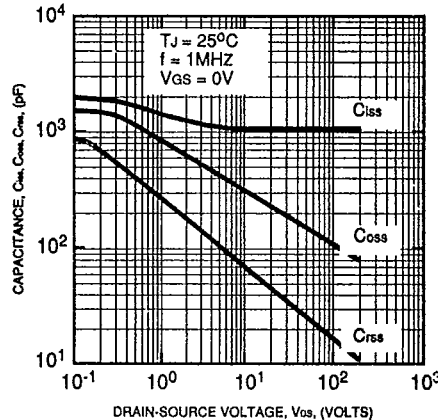
COMMON SOURCE OUTPUT
CHARACTERISTICS (TYPICAL)
J935



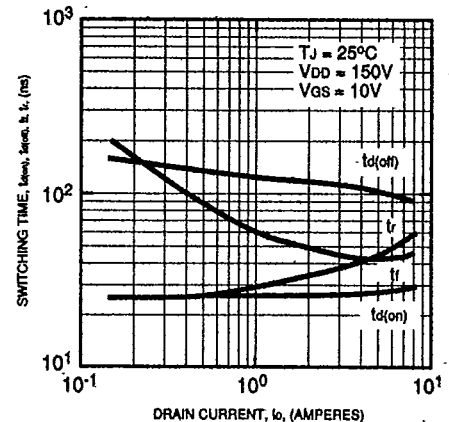
COMMON SOURCE OUTPUT
CHARACTERISTICS (TYPICAL)
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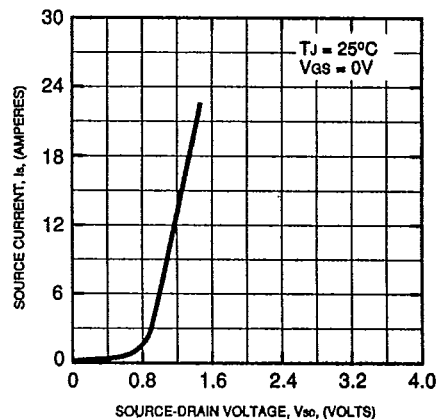
CAPACITANCE VS. DRAIN-SOURCE VOLTAGE
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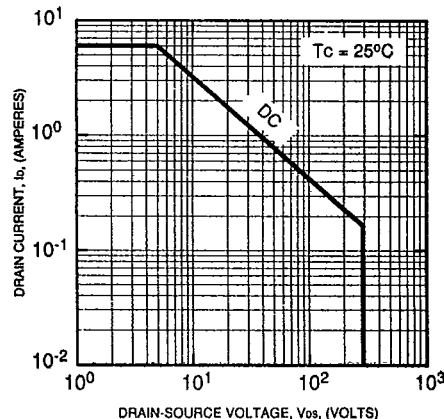
SWITCHING CHARACTERISTICS
(TYPICAL)
J935



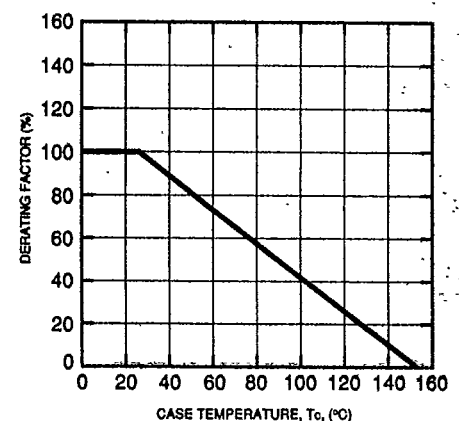
SOURCE-DRAIN DIODE
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FORWARD BIAS SAFE OPERATING AREA
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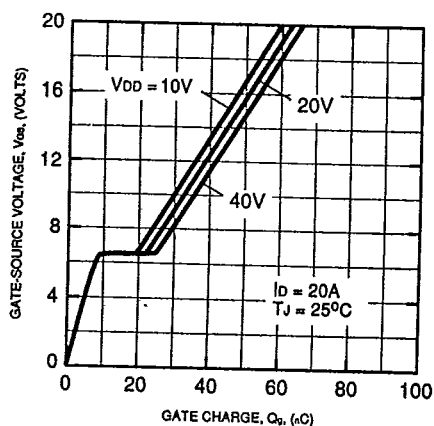
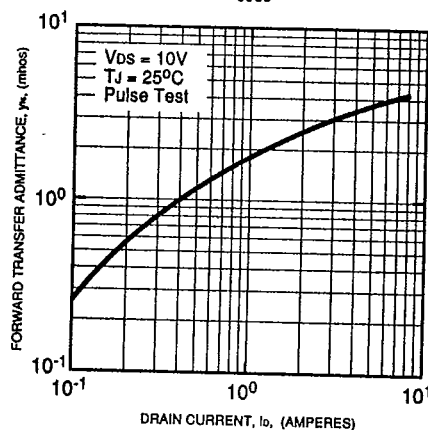
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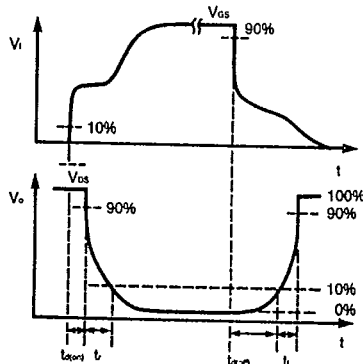
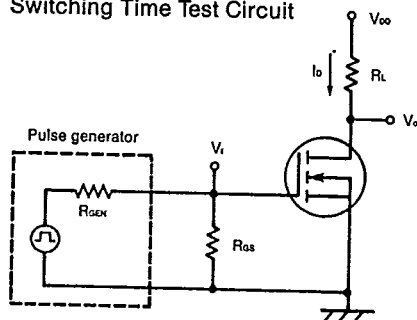
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